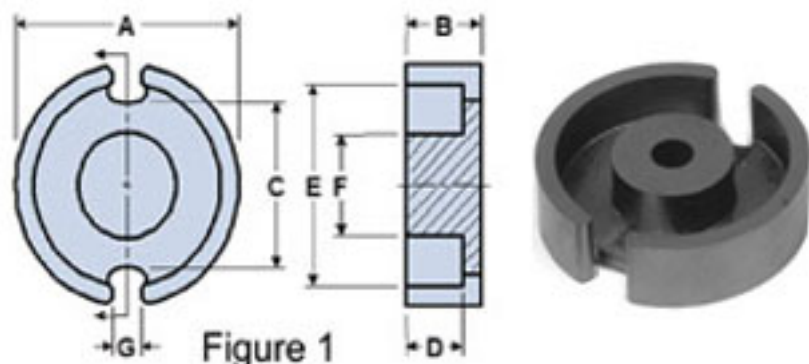




Part Number: 5678090621
 Frequency Range: Dimensions
 Description: 78 POT CORE
 Application: Inductive Components
 Where Used: Closed Magnetic Circuit
 Part Type: Pot Cores
 Generic Name: P9/5S

Mechanical Specifications

Weight: 1.000 (g) per Set

Part Type Information

P9/5S, P11/7S, P14/8, P18/11, P22/13, P26/16, P30/19, P36/22

Pot cores have found application in all types of inductive devices. The core configuration provides a high degree of self-shielding. It also facilitates gapping to enhance utility for a variety of magnetic designs.

-Pot cores can be supplied with the center post gapped to a mechanical dimension or an AL value.

-AL value is measured at 1 kHz, B < 10 gauss.

-Weight indicated is per pair or set.

Mechanical Specifications

Dim	mm	mm tol	nominal inch	inch misc.
A	9.15	±0.15	0.360	-
B	2.65	±0.1	0.104	-
C	5.65	±0.15	0.222	-
D	1.80	min	0.071	min
E	7.50	min	0.295	min
F	3.80	±0.1	0.150	-
G	2.10	±0.3	0.083	-
H	-	-	-	-
J	-	-	-	-
K	-	-	-	-

Electrical Specifications

Typical Impedance (Ω)	

Electrical Properties	
A_L (nH)	1200 ±25%
A_e (cm ²)	0.11200
$\Sigma I/A$ (cm ⁻¹)	12.00
l_e (cm)	1.35
V_e (cm ³)	0.15200
A_{min} (cm ²)	.090

Land Patterns

V	W ref	X	Y	Z
-	-	-	-	-
-	-	-	-	-

Winding Information

Turns	Wire	1st Wire	2nd Wire
Tested	Size	Length	Length
-	-	-	-

Reel Information

Tape Width mm	Pitch mm	Parts 7 " Reel	Parts 13 " Reel	Parts 14 " Reel
-	-	-	-	-

Package Size

Pkg Size
- (-)

Connector Plate

# Holes	# Rows
-	-

Legend

+ Test frequency

Preferred parts, the suggested choice for new designs, have shorter lead times and are more readily available.

The column H(Oe) gives for each bead the calculated dc bias field in oersted for 1 turn and 1 ampere direct current. The actual dc H field in the application is this value of H times the actual NI (ampere-turn) product. For the effect of the dc bias on the impedance of the bead material, see figures 18-23 in the application note How to choose Ferrite Components for EMI Suppression.

A ½ turn is defined as a single pass through a hole.

$\Sigma I/A$ - Core Constant

A_e - Effective Cross-Sectional Area

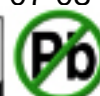
A_L - Inductance Factor ($\frac{L}{N^2}$)

N/AWG - Number of Turns/Wire Size for Test Coil

l_e - Effective Path Length

V_e - Effective Core Volume

NI - Value of dc Ampere-turns



Ferrite Material Constants

Specific Heat	0.25 cal/g/°C
Thermal Conductivity	3.5 - 4.5 mW/cm - °C
Coefficient of Linear Expansion	8 - 10x10 ⁻⁶ /°C
Tensile Strength	4.9 kgf/mm ²
Compressive Strength	42 kgf/mm ²
Young's Modulus	15x10 ³ kgf/mm ²
Hardness (Knoop)	650
Specific Gravity	≈ 4.7 g/cm ³

The above quoted properties are typical for Fair-Rite MnZn and NiZn ferrites.

See next page for further material specifications.



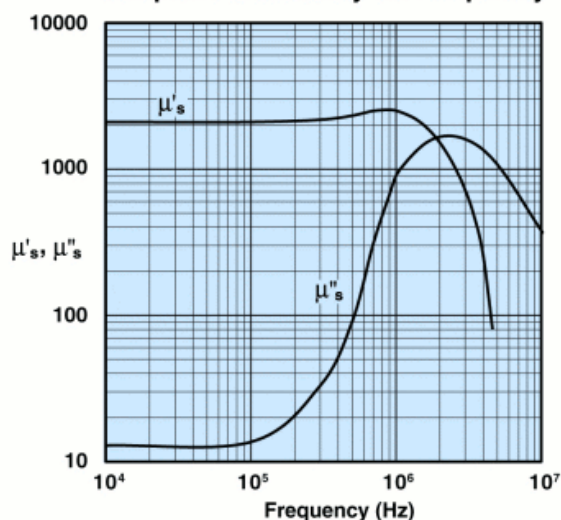
A MnZn ferrite specifically designed for power applications for frequencies up to 200 kHz.

RFID rods, toroids, U cores, and E&I cores are all available in 78 material.

78 Material Characteristics:

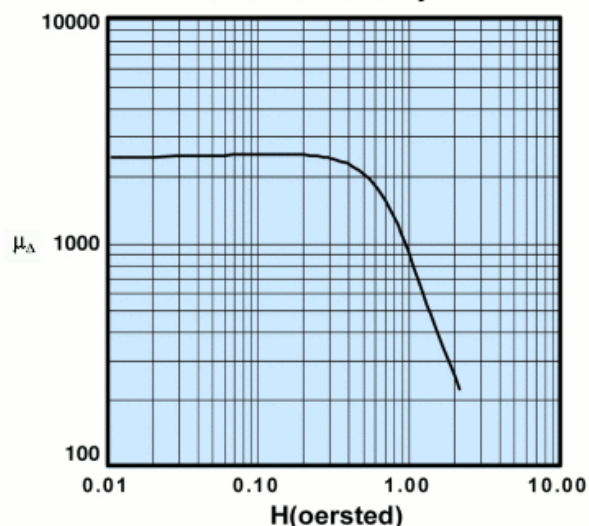
Property	Unit	Symbol	Value
Initial Permeability @ B < 10 gauss		μ_i	2300
Flux Density @ Field Strength	gauss oersted	B H	4800 5
Residual Flux Density	gauss	B_r	1500
Coercive Force	oersted	H_c	0.20
Loss Factor @ Frequency	10^{-6} MHz	$\tan \delta \mu_i$	4.5 0.1
Temperature Coefficient of Initial Permeability (20 -70°C)	%/°C		1.0
Curie Temperature	°C	T_c	>200
Resistivity	Ω cm	ρ	2×10^2

Complex Permeability vs. Frequency

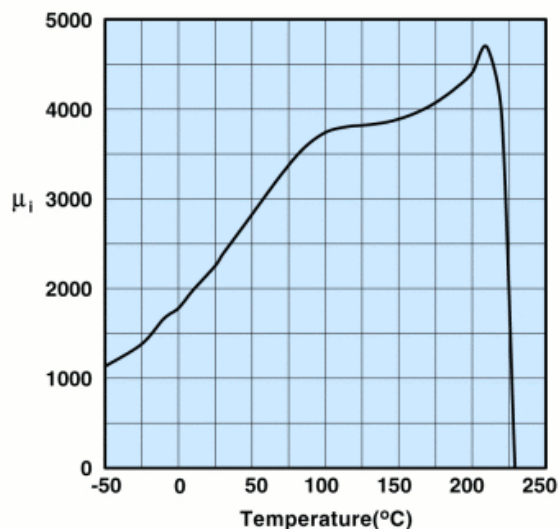


Measured on an 18/10/6mm toroid using the HP 4284A and the HP 4291A.

Incremental Permeability vs. H

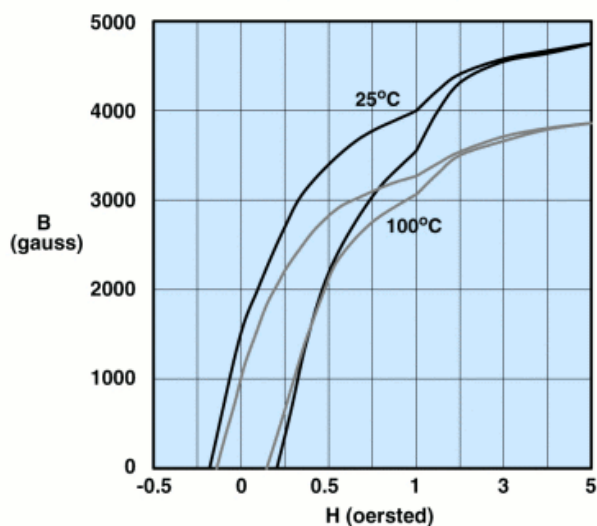


Initial Permeability vs. Temperature



Measured on an 18/10/6mm toroid at 100kHz.

Hysteresis Loop



Measured on an 18/10/6mm toroid at 10kHz.

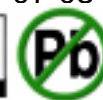


Fair-Rite Products Corp. Your Signal Solution®

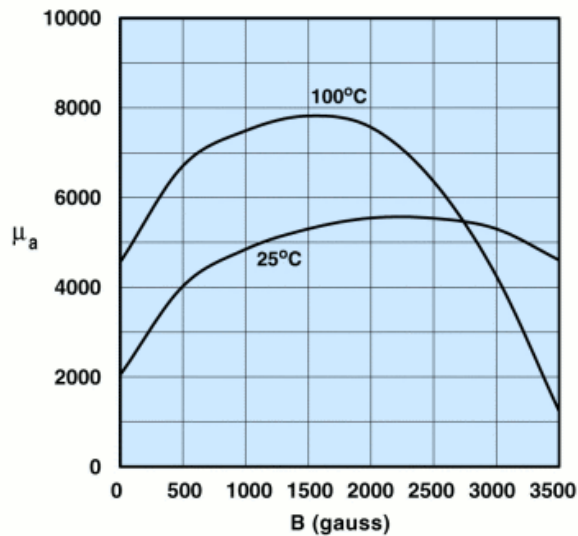
Ferrite Components for the Electronics Industry

Fair-Rite Products Corp. PO Box J, One Commercial Row, Wallkill, NY 12589-0288
Phone: (888) 324-7748 www.fair-rite.com

Fair-Rite Product's Catalog
Part Data Sheet, 5678090621
Printed: 2013-07-03

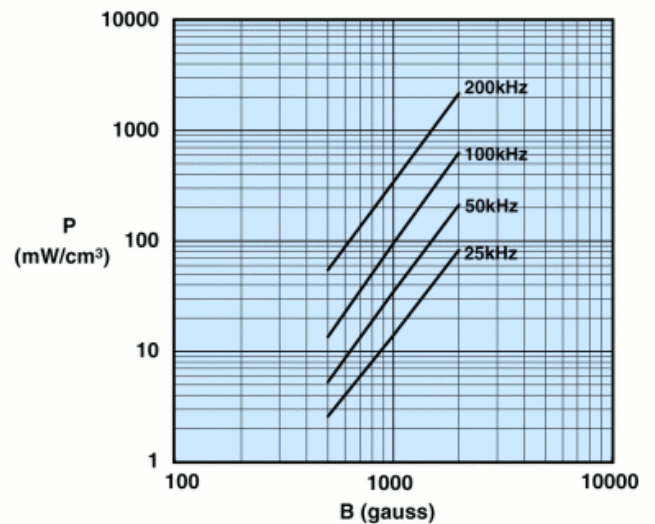


Amplitude Permeability vs. Flux Density



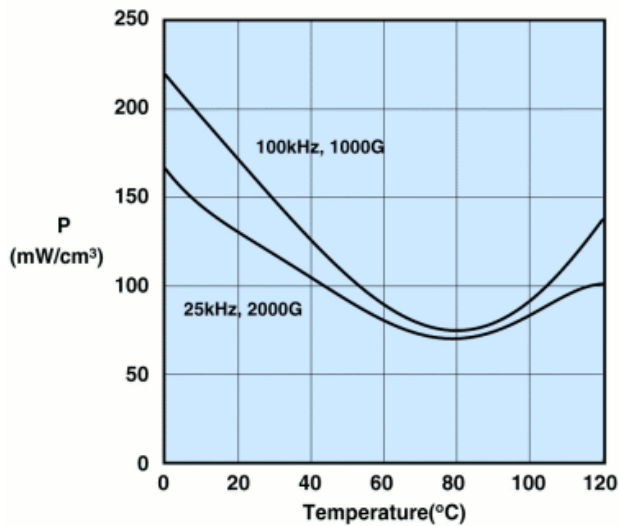
Measured on an 18/10/6mm toroid at 10kHz.

Power Loss Density vs. Flux Density



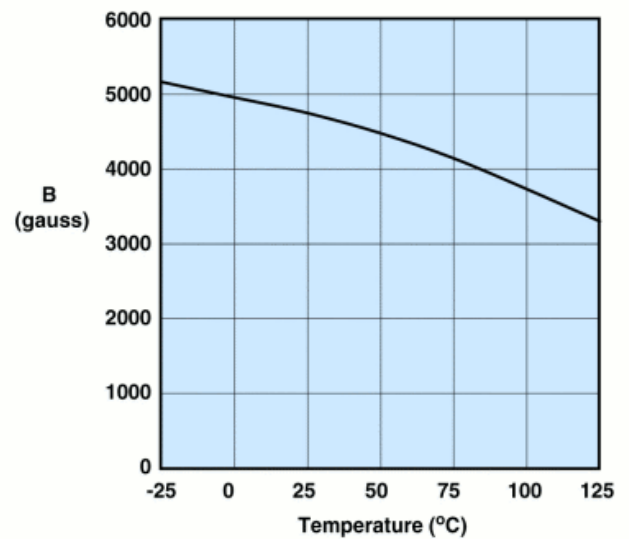
Measured on an 18/10/6mm toroid using the Clarke Hess 258 VAW at 100°C

Power Loss Density vs. Temperature



Measured on an 18/10/6mm toroid using the Clarke Hess 258 VAW.

Flux Density vs. Temperature



Measured on an 18/10/6 mm toroid at 10kHz and H=5 oersted.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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